# **QDL**ASER

## QLD103E-xx50

1030 / 1064 nm >50mW DFB Laser TO-CAN

C00144-02 July 2016



## 1. DESCRIPTION

The QLD103E-xx50 is a 1030 / 1064-nm distributed feedback (DFB) laser suitable for various applications, such as seeder, measurement, sensing, frequency doubling and etc. The laser is mounted into a TO-56 header including a monitor PD for optical power control and hermetic sealed with a flat type cap.

#### 2. FEATURES

- Single longitudinal mode operation at 1030 nm and 1064 nm
- CW and short pulsed operation
- Φ5.6mm TO-CAN package
- Monitor PD included

### 3. APPLICATIONS

- Seeder
- Measurement
- Sensing
- Frequency doubling
- Short pulse generation

## 4. ABSOLUTE MAXIMUM RATINGS

 $(T_c = 25^{\circ}C, unless otherwise specified)$ 

PARAMETER	SYMBOL	RATING	UNIT
Optical Output power	Po	60	mW
LD Forward Current	$I_{\mathrm{F}}$	180	mA
LD Reverse Voltage	$V_{RLD}$	2	V
PD Forward Current	$I_{\mathrm{FPD}}$	2	mA
PD Reverse Voltage	$V_{RPD}$	10	V
Operation Temperature	$T_{c}$	15 to 45	°C
Storage Temperature	$T_{stg}$	-40 to 85	°C
Lead Soldering Temperature (10 s)	$T_{\rm sld}$	260	°C



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QLD103E-xx50 C00144-02

## 5. OPTICAL AND ELECTRICAL CHARACTERISTICS

 $(T_{LD} = 25^{\circ}C, \text{ unless otherwise specified})$ 

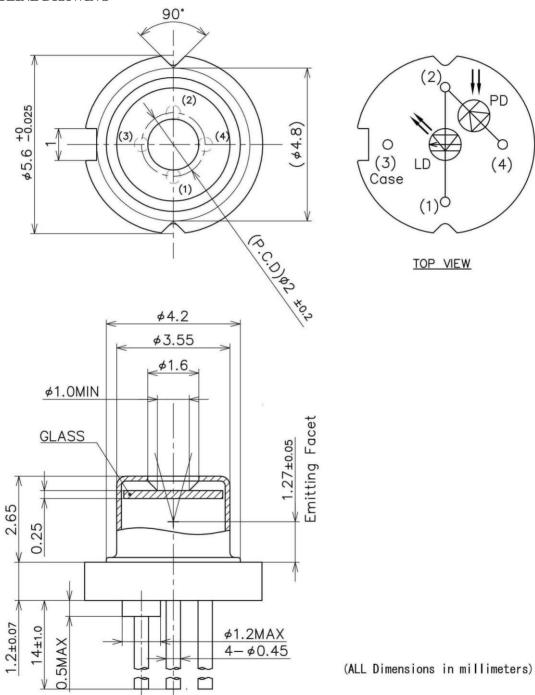
PARA	AMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Peak QLD103E-64		2	CW D _50 mW	1059*	1064	1069*	nm
Wavelength	QLD103E-3050	$\lambda_{ m p}$	$CW, P_O = 50 \text{ mW}$	1025*	1030	1035*	nm
Temperature C	coefficient of $\lambda_p$	$d\lambda_p/dT$	CW	-	0.08	-	nm/K
Current Coeffic	cient of $\lambda_p$	$d\lambda_p/dI$	CW	-	0.008	-	nm/mA
Optical Output	Power	Po	CW	50	-	-	mW
Threshold Curr	rent	$I_{th}$	CW	-	20	-	mA
Operation Curr	ent	$I_{op}$	$CW, P_O = 50 \text{ mW}$	-	100	150	mA
Operation Volt	age	$V_{op}$	$CW, P_O = 50 \text{ mW}$	-	1.5	2.0	V
Sidemode Supp	pression Ratio	SMSR	$CW, P_O = 50 \text{ mW}$	-	40	-	dB
Far filed patter	n horizontal	$\theta_{h}$	$CW, P_O = 50 \text{ mW}$	-	10	-	deg.
Far filed patter	n vertical	$\theta_{ m v}$	$CW, P_O = 50 \text{ mW}$	-	22	-	deg.
Monitor PD Cu	urrent	Im	$CW$ , $P_O = 50 \text{ mW}$ , $V_{RPD} = 5 \text{ V}$	-	250	-	μΑ
Dark current (I	PD)	I <sub>d</sub>	V <sub>RPD</sub> =5 V	-	-	20	nA

<sup>\*</sup>Peak wavelength torelance of +/- 1nm is available as an option.



QLD103E-xx50 C00144-02

## 6. OUTLINE DRAWING





QLD103E-xx50 C00144-02

### 7. NOTICE

#### Safety Information

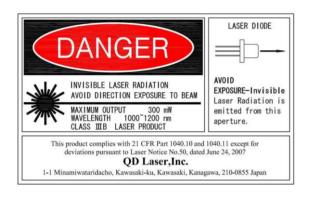
This product is classified as Class 3B laser product, and complies with 21 CFR Part 1040.10. Please do not take a look laser lighting in operations since laser devices may cause troubles to human eyes. Please do not eat, burn, break and make chemical process of the products since they contain GaAs material.

## Handling products

Semiconductor lasers are easily damaged by external stress such as excess temperature and ESD. Please pay attention to handling products, and use within range of maximum ratings. QD Laser takes no responsibility for any failure or unusual operation resulting from improper handling, or unusual physical or electrical stress.

#### RoHS

This product conforms to RoHS compliance related EU Directive 2011/65/EU.







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